Scheelite-related M^{II}_xBi_{1-x}V_{1-x}Mo_xO₄ (M^{II} – Ca, Sr) Solid Solutions Based Photoanodes for Enhanced Photoelectrochemical Water Oxidation

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Fig. S1 Experiment Apparatus



Fig. S2 Single crystals of Ca_{0.126}Bi_{0.874}V_{0.874}Mo_{0.126}O₄ photo (a) and SEM image of surfaces (insert is the associated EDS).

Crystal data		
Formula	$Bi_{0,874}Ca_{0,126}V_{0,874}Mo_{0,126}O_{4}$	$Bi_{0.5}Sr_{0.5}V_{0.5}Mo_{0.5}O_{4}$
Formula weight	308.3	285.74
Crystal system	Tetragonal	Tetragonal
Space group	$I4_1$ (N80)	$I4_{1}/a$ (N88)
a, Å	5.1519(4)	5.26909(8)
c, Å	11.6330(8)	11.89254(19)
V, Å ³	308.76(4)	330.177(9)
Formula units, Z	4	4
Radiation type	Mo $K\alpha$ ($\lambda = 0.71073$ Å)	Cu $K\alpha$ (λ = 1.540598 Å)
Dx (Mg m-3)	6.632	
F(000)	530	
μ (mm ⁻¹)	52.95	
Temperature (K)	293	293
Data collection		
Diffractometer	Oxford Xcalibur-3 CCD	Shimadzu LabX XRD-
	area-detector	6000
Scan	ϕ and ω	$2\theta_{\text{step}} = 0.02^{\circ}$
Absorption correction:	multi-scan (Blessing,	curp.
1	1995)	
Tmin, T max = 1	0.289, 1	
Measured reflections	2400	
Independent reflections	579	
Reflections with $I > 2\sigma(I)$	489	
R _{int}	0.070	
θ_{\min}	36.2°	$2\theta_{\min} = 10.041^{\circ}$
θ_{\max}	4.3°	$2\theta_{\rm max} = 105.061^{\circ}$
h, k, l	$-8 \rightarrow 7, -7 \rightarrow 8, -11 \rightarrow 19$	
Refinement		
Refinement on $F^2 R[F^2]$	0.054	
$> 2\sigma(F^2)$]		
$wR(F^2)$	0.123	
S	1.90	
Reflections	579	
Parameters	30	34
$\Delta \rho_{\rm max}, \Delta \rho_{\rm min} ({\rm e} \cdot {\rm \AA}^{-3})$	2.69, -5.44	
Friedel pairs	197	
R _p		9.660
$R_{\rm wp}$		12.993
R _{exp}		4.474

Table S1 Structural details for single-crystal $Bi_{0.874}Ca_{0.126}\,V_{0.874}Mo_{0.126}\,O_4$ and powdered $Bi_{0.5}Sr_{0.5}V_{0.5}Mo_{0.5}O_4$

$Bi_{0.5}Sr_{0.5}V_{0.5}Mo_{0.5}O_4$								
Atom	Site	Occ.	x	У	Z			
$Bi_{0.874} Ca_{0.126} V_{0.874} Mo_{0.126} O_4$								
Bil	4a	0.874(7)	0.5	0.5	0.1248(3)			
Cal	4a	0.126(7)	0.5	0.5	0.1248(3)			
V1	4a	0.874(7)	1	0	0.1267(9)			
Mo1	4a	0.126(7)	1	0	0.1267(9)			
O1	8b	1	0.8504(19)	0.250(3)	0.0438(18)			
O2	8b	1	0.245(3)	0.131(2)	0.2027(19)			
Bi _{0.5} Sr _{0.5} V _{0.5} Mo _{0.5} O ₄								
Bil	4a	0.5	0	0.25	0.625			
Cal	4a	0.5	0	0.25	0.625			
V1	4a	0.5	-0.5	-0.25	0.625			
Mo1	4a	0.5	-0.5	-0.25	0.625			
O1	16f	1	-0.7479(13)	-0.3743(14)	0.5418(6)			

Table S2. Atomic coordinates for $Bi_{0.874} Ca_{0.126} V_{0.874} Mo_{0.126} O_4$ and $Bi_{0.5} Sr_{0.5} V_{0.5} Mo_{0.5} O_4$

BiVO ₄					5 Spectrum 13
	Found Calculated		lated	10-	
	Wt. %	At. %	Wt. %	At. %	•- 0
Bi	65.50	17.7	64.51	16.67	
V	16.34	18.1	15.73	16.67	
0	18.17	64.2	19.76	66.66	
					0 1 2 3 4 5 6 7 8 9 keV
		CBVM	[1		
	For	ind	Calcu	lated	
	Wt. %	At. %	Wt. %	At. %	
Bi	61.20	15.9	60.37	15.0	25-
Mo	3.73	2.1	3.08	1.67	
V	15.21	16.2	14.72	15.0	15-
Ca	0.81	1.1	1.29	1.67	
0	19.05	64.7	20.54	66.66	
		SRVM	1		■ 前面4
	For	ind	Calcu	lated	
	Wt. % At. % Wt. % At. %		At. %		
Bi	60.55	16.1	59.47	15.0	3-
Mo	3.97	2.3	3.03	1.67	
V	14.97	16.3	15.0	15.0	
Sr	2.08	1.3	2.77	1.67	
0	18.43	64.0	20.23	66.66	
	1	CBVM	2		B Spectrum 1
Found Calculated				lated	
_	Wt. %	<u>At. %</u>	Wt. %	At. %	
Bi	59.65	15.7	55.89	13.33	
MO	5.99	3.4	6.42	3.34	about the second se
	14.74	15.9	13.62	13.33	
	1.18	1.0	2.68	5.54	
U	18.44	03.4	21.39	00.00	
					0 1 2 3 4 5 6 7 8 9 keV

Table S3 The EDS data for $M^{II}_{1-x}Bi_xV_xMo_{1-x}O_4$ (x =0-1) Solid Solutions

SBVM2					8
	Found <i>Calculated</i>		lated	<u>,-</u>	
	Wt. %	At. %	Wt. %	At. %	
Bi	57.70	15.3	54.17	13.33	3- 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1
Mo	5.05	2.9	6.22	3.34	
V	14.43	15.7	13.20	13.33	
Sr	4.58	2.9	5.68	3.34	
0	18.24	63.2	20.73	66.66	
					$0 = \begin{bmatrix} 1 & 1 & 1 & 1 & 1 & 1 & 1 & 1 & 1 & 1$
		CBVM	3		E Spectrum 2
	Fou	nd	Calcu	lated	
	Wt. %	At. %	Wt. %	At. %	6
Bi	57.76	14.9	51.01	11.67	
Mo	8.42	4.7	10.04	5.0	4 na -
V	11.00	12.7	12.44	11.67	a <mark>- a</mark> la constante de la constan
Ca	2.93	3.9	4.19	5.0	22 N
0	18.89	63.8	22.32	66.66	
SBVM3					o V
	Found <i>Calculated</i>				
	Wt. %	At. %	Wt. %	At. %	
Bi	54.11	14.3	48.6	13.33	8
Mo	9.06	5.2	9.56	3.34	
V	11.96	13.0	11.85	13.33	
Sr	6.55	4.1	8.73	3.34	
0	18.32	63.4	21.26	66.66	
					2
					134 E U I U E N E 2 2 U
		CBVM	[5		- O B Spectrum 7
Found <i>Calculated</i>					
	Wt. %	At. %	Wt. %	At. %	
Bi	42.59	9.8	39.89	8.34	5 - Md
Mo	20.61	10.3	18.31	8.33	
V	9.44	8.9	9.72	8.34	
Ca	6.20	7.4	7.65	8.33	
0	21.16	63.6	24.43	66.66	2-
					$0 = \frac{1}{1} + \frac{1}{2} + $

SBVM5					E O
	Found <i>Calculated</i>		lated		
	Wt. %	At. %	Wt. %	At. %	
Bi	38.45	9.5	36.57	8.34	
Mo	18.38	9.9	16.79	8.33	8 2−
V	9.68	9.8	8.91	8.34	
Sr	14.13	8.3	15.33	8.33	
0	19.36	62.6	22.4	66.66	2
					0 1 2 3 4 5 6 7
		CBVM	[7		10 O Spectrum 3
	For	ind	Calcu	lated	
	Wt. %	At. %	Wt. %	At. %	
Bi	33.86	7.3	26.43	5.0	
Mo	27.75	13.0	28.32	11.67	
V	5.77	5.1	6.44	5.0	
Ca	10.18	11.4	11.83	11.67	
	22.44	63.2	26.98	66.66	
		SBVM	7		Spectrum 10
Found Calculated					5
	Wt. %	At. %	Wt. %	At. %	
Bi	27.35	6.4	23.18	5.0	
Mo	23.79	12.1	24.83	11.67	
V	6.19	5.9	5.65	5.0	2
Sr	21.92	12.2	22.68	11.67	
0	20.75	63.4	23.66	66.66	
		CBVM	[8		8 - 0 Mo
	Fou	ınd	Calcu	lated	
	Wt. %	At. %	Wt. %	At. %	6
Bi	20.40	3.8	18.59	3.34	
Mo	34.28	13.9	34.15	13.33	ê 4-
V	3.82	2.9	4.53	3.34	
Ca	14.89	14.5	14.26	13.33	
0	26.61	64.9	28.47	66.66	
					$ \begin{array}{c} 0 \\ - \\ 0 \\ - \\ 0 \\ - \\ 2 \\ - \\ 2 \\ - \\ 2 \\ - \\ 2 \\ - \\ 2 \\ - \\ -$

SBVM8					- Spectrum 11
	Found		Calculated		4-
	Wt. %	At. %	Wt. %	At. %	
Bi	12.53	2.7	15.90	3.34	
Mo	33.0	15.5	29.21	13.33	
V	3.43	3.0	3.87	3.34	
Sr	28.31	14.6	26.67	13.33	
0	22.73	64.2	24.35	66.66	
					0 1 2 3 4 5 6 7 8 9 keV
					- Q Spectrum S
	Г			1 , 1	
		ind	Calculated		
D •	Wt. %	<u>At. %</u>	Wt. %	At. %	6
BI	11.98	2.2	9.84	1.6/	
NIO	42.10	16.8	40.65	15.0	
	2.01	1.5	2.4	1.6/	
Ca	1/.90	1/.1	16.98	15.0	
0	26.01	62.4	30.13	66.66	
					$ = 0^{-1} \begin{bmatrix} 0^{-1} \\ 0 \\ 1 \end{bmatrix} = 2 \begin{bmatrix} 0^{-1} \\ 2 \end{bmatrix} = 3 \begin{bmatrix} 0^{-1} \\ 0 \end{bmatrix} = 4 \begin{bmatrix} 0^{-1} \\ 0 \end{bmatrix} =$
					- //
		SBVM	[9		5 Spectrum 12
	Found		Calculated		
	Wt. %	At. %	Wt. %	At. %	
Bi	6.06	1.3	8.19	1.67	
Mo	35.64	16.6	33.84	15.0	
V	1.18	1.0	2.0	1.67	
Sr	34.42	17.6	30.9	15.0	
0	22.69	63.5	25.07	66.66	

Formula	Abr.	a	c	V	Eg
BiVO ₄ *	-	<i>a</i> = 5.197	<i>c</i> =11.702	309.9	2.34
		<i>b</i> = 5.096	$\beta = 90.4$		
$Ca_{0.1}Bi_{0.9}V_{0.9}Mo_{0.1}O_4$	CBVM1	5.1433(2)	11.6733(1)	308.81(3)	2.47
$Ca_{0.2}Bi_{0.8}V_{0.8}Mo_{0.2}O_4$	CBVM2	5.1553(1)	11.6512(2)	309.84(1)	2.50
$Ca_{0.3}Bi_{0.7}V_{0.7}Mo_{0.3}O_4$	CBVM2	5.1603(3)	11.1651(1)	310.43(3)	2.51
$Ca_{0.5}Bi_{0.5}V_{0.5}Mo_{0.5}O_4$	CBVM5	5.2065(1)	11.1451(1)	310.96(2)	2.72
$Ca_{0.7}Bi_{0.3}V_{0.3}Mo_{0.7}O_4$	CBVM7	5.2231(1)	11.4237(2)	311.61(1)	3.08
CaMoO ₄ [19]	-	5.3255	11.4298	331.8	3.64
$Sr_{0.1}Bi_{0.9}V_{0.9}Mo_{0.1}O_4$	SBVM1	5.16087(4)	11.7229(1)	313.18(3)	2.35
$Sr_{0.2}Bi_{0.8}V_{0.8}Mo_{0.2}O_4$	SBVM1	5.1882(1)	11.7713(3)	316.85(2)	2.58
$Sr_{0.3}Bi_{0.7}V_{0.7}Mo_{0.3}O_4$	SBVM1	5.2154(2)	11.8172(1)	321.44(2)	2.61
$Sr_{0.5}Bi_{0.5}V_{0.5}Mo_{0.5}O_4$	SBVM1	5.2691(3)	11.8926(2)	330.182(1)	2.81
$Sr_{0.7}Bi_{0.3}V_{0.3}Mo_{0.7}O_4$	SBVM1	5.3204(1)	11.9557(1)	338.43(2)	2.95
$Sr_{0.8}Bi_{0.2}V_{0.2}Mo_{0.8}O_4$	SBVM1	5.3473(4)	11.98(2)	342.67(2)	3.12
$Sr_{0.9}Bi_{0.1}V_{0.1}Mo_{0.9}O_4$	SBVM1	5.3696(1)	11.99(1)	345.82(4)	3.28
SrMoO ₄ [30]	-	5.222(1)	11.425(3)	332.1	4.06

Table S4 Lattice Parameters (Å or Å³) and calculated Eg values of $M^{II}_{1-x}Bi_xV_xMo_{1-x}O_4$ (x = 0-1) Solid Solutions

*BiVO₄ is indexed in monoclinic crystal system¹⁹



Fig. S3 SEM images of (a) SBVM5 powder (the insert is the associated EDS) and BiVO₄ prepared under the same conditions (b).



Fig. S4 Determination of bandgap values for pure BiVO₄ and $M^{II}_{1-x}Bi_xV_xMo_{1-x}O_4$ (*x* =0-1) solid solutions calculated using Kubelka –Munk function.



Fig. S5 Comparative testing of CBVM1-FTO performance prepared by different methods.

Fig. S6 Comparative testing of SBVM1-FTO performance prepared by different methods.

Fig. S7 SEM image and EDX mapping for CBVM-1 sample on the FTO surface prepared by spin-coating (a) and dropped –coating (b) methods after annealing at 500° C.

Fig. S8 The results of I-t tests and photocurrent – potential curves for FTO.

Fig. S9 Exfoliation of CaMoO₄-Nafion film from FTO surface and the view of the SrMoO₄-FTO electrode dried at 60°C.

Fig. S10 Comparative testing of CBVM1-FTO performance after final annealing at different temperatures (a) photocurrent –time curves; (b) photocurrent–potential curves; (c) dependencies photocurrent–potential, that show the change in LSV values (d) the results of EIS spectroscopy (the insert – a high-frequency region of the spectra). All measurements have been taken in 0.5 M Na₂SO₄ solution. The chopped light with power of 100 mW ⋅ cm⁻².

Fig. S11 The equivalent scheme for EIS measurement: R_s – solution resistance, R_{ct} – the resistance of electron transfer on a photoanode; Q_H – constant phase element (CPE), represents Helmholtz layer capacitance; Q_{SC} – constant phase element (CPE), represents space charge layer capacitance; R_{SC} is the space charge separation resistance Q is the constant phase element (CPE). Since the charge transport and transfer process is considered to be normally much faster in the bulk than that in the semiconductor-electrolyte interface, the low frequency response has been assigned to the semiconductor-electrolyte charge transfer behavior (R_{ct} and Q_H) while the high frequency response has been designated to the behavior in the semiconductor bulk ($_{RSC}$ and Q_{SC}) correspondingly.

Fig. S12 SEM images and EDX mapping for samples SBVM-1 (a) and CBVM-1 (b) on the FTO surface after annealing at 350°C.

Fig. S13 UV-Vis diffuse reflectance spectra for electrodes after annealing at 350 and 500 °C: (a) CBMV-1-350-FTO and CBMV-1-500-FTO; (b) SBMV-1-350-FTO and SBMV-1-500-FTO.

Fig. S14 The results of I-t tests for electrodes based on solid solution $M^{II}_{x}Bi_{1-x}V_{1-x}Mo_{x}O_{4}$ (where $M^{II} - Ca$, Sr) within the values x = 0.5, 0.7, 0.8 i 0.9: (a, b) after 10 min of testing and (c,d) after photocurrent stabilization CBMV(4-7)-FTO, SBVM(4-7)-FTO, BiVO₄-FTO.

Fig. S15 Photocurrent – potential curves for CBVM-FTO (a) and SBVM-FTO (b) photoanodes.